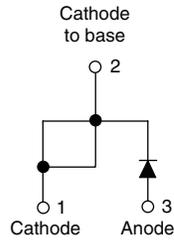
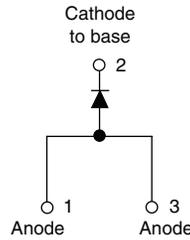


Ultrafast Soft Recovery Diode, 60 A FRED Pt™

60EPU06PbF

TO-247AC modified
60APU06PbF

TO-247AC

FEATURES

- Ultrafast recovery
- 175 °C operating junction temperature
- Lead (Pb)-free ("PbF" suffix)
- Designed and qualified for industrial level


RoHS*
COMPLIANT

BENEFITS

- Reduced RFI and EMI
- Higher frequency operation
- Reduced snubbing
- Reduced parts count

DESCRIPTION/APPLICATIONS

These diodes are optimized to reduce losses and EMI/RFI in high frequency power conditioning systems.

The softness of the recovery eliminates the need for a snubber in most applications. These devices are ideally suited for HF welding, power converters and other applications where switching losses are not significant portion of the total losses.

PRODUCT SUMMARY

t_{rr} (typical)	34 ns
$I_{F(AV)}$	60 A
V_R	600 V

ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS
Cathode to anode voltage	V_R		600	V
Continuous forward current	$I_{F(AV)}$	$T_C = 116\text{ °C}$	60	A
Single pulse forward current	I_{FSM}	$T_C = 25\text{ °C}$	600	
Maximum repetitive forward current	I_{FRM}	Square wave, 20 kHz	120	
Operating junction and storage temperatures	T_J, T_{Stg}		- 55 to 175	°C

ELECTRICAL SPECIFICATIONS ($T_J = 25\text{ °C}$ unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	V_{BR}, V_R	$I_R = 100\ \mu\text{A}$	600	-	-	V
Forward voltage	V_F	$I_F = 60\text{ A}$	-	1.35	1.68	
		$I_F = 60\text{ A}, T_J = 125\text{ °C}$	-	1.20	1.42	
		$I_F = 60\text{ A}, T_J = 175\text{ °C}$	-	1.11	1.30	
Reverse leakage current	I_R	$V_R = V_R\text{ rated}$	-	-	50	μA
		$T_J = 150\text{ °C}, V_R = V_R\text{ rated}$	-	-	500	
Junction capacitance	C_T	$V_R = 600\text{ V}$	-	39	-	pF

* Pb containing terminations are not RoHS compliant, exemptions may apply

60EPU06PbF/60APU06PbF



Vishay High Power Products Ultrafast Soft Recovery Diode,
60 A FRED Pt™

DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
Reverse recovery time	t _{rr}	I _F = 1 A, di _F /dt = 200 A/μs, V _R = 30 V		-	34	45	ns
		T _J = 25 °C	I _F = 60 A di _F /dt = 200 A/μs V _R = 200 V	-	81	-	
		T _J = 125 °C		-	164	-	
Peak recovery current	I _{RRM}	T _J = 25 °C	I _F = 60 A di _F /dt = 200 A/μs V _R = 200 V	-	7.4	-	A
		T _J = 125 °C		-	17.0	-	
Reverse recovery charge	Q _{rr}	T _J = 25 °C	I _F = 60 A di _F /dt = 200 A/μs V _R = 200 V	-	300	-	nC
		T _J = 125 °C		-	1394	-	

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
Thermal resistance, junction to case	R _{thJC}			-	-	0.63	K/W
Thermal resistance, case to heatsink	R _{thCS}	Mounting surface, flat, smooth and greased		-	0.2	-	
Weight				-	5.5	-	g
				-	0.2	-	oz.
Mounting torque				1.2 (10)	-	2.4 (20)	N · m (lbf · in)
Marking device		Case style TO-247AC modified		60EPU06			
		Case style TO-247AC		60APU06			



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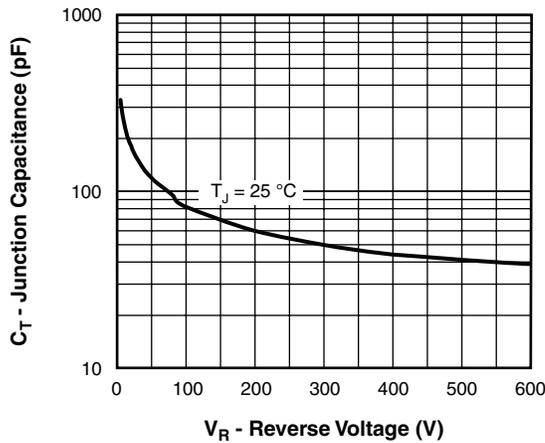
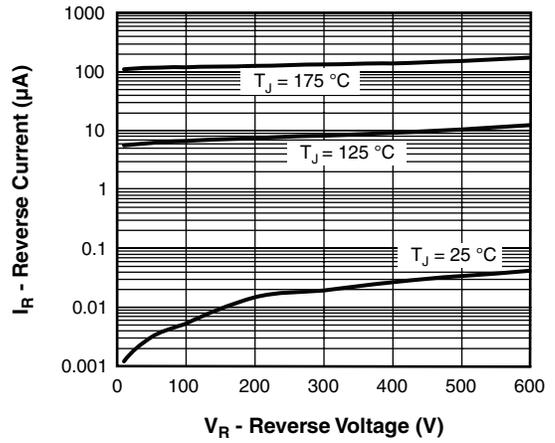
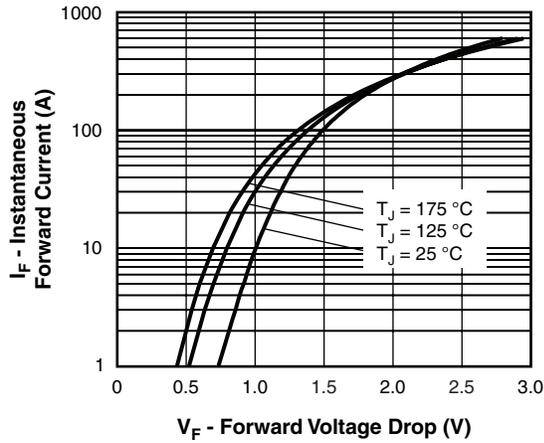
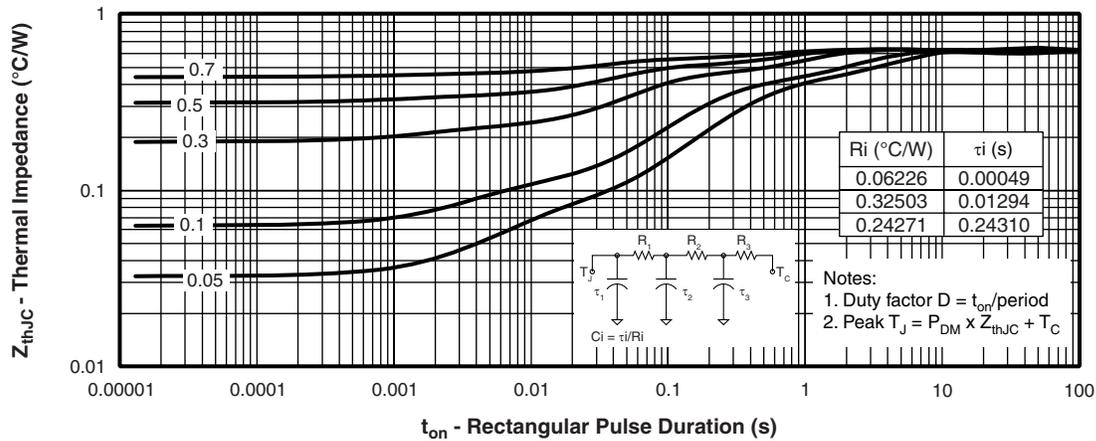


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage



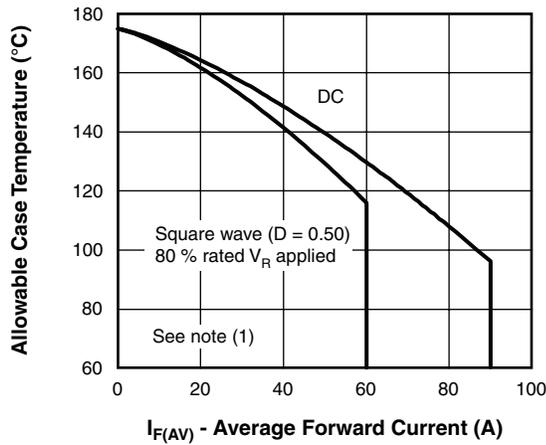


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

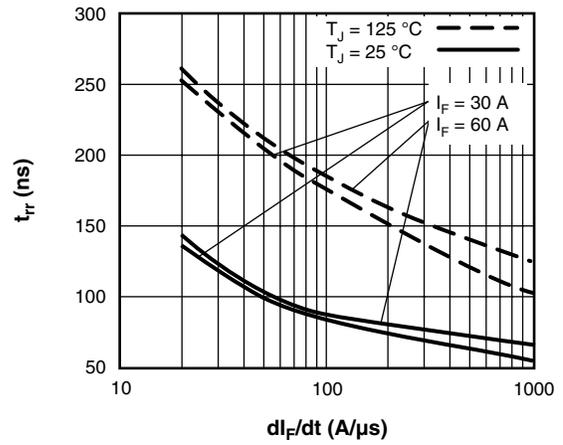


Fig. 7 - Typical Reverse Recovery Time vs. di_F/dt

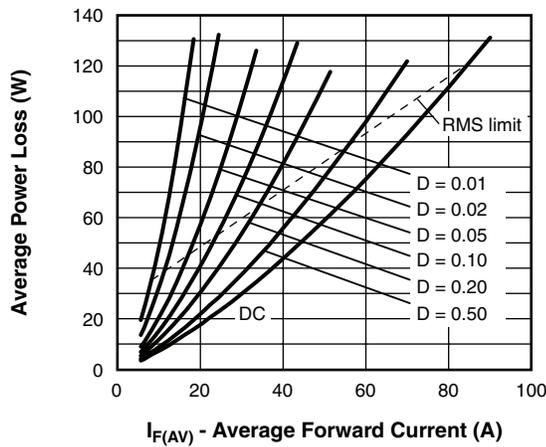


Fig. 6 - Forward Power Loss Characteristics

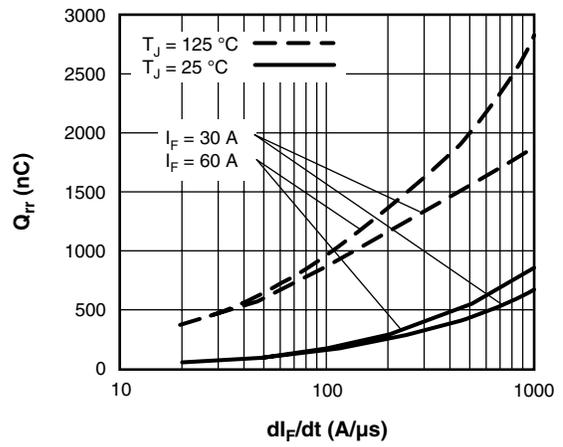


Fig. 8 - Typical Stored Charge vs. di_F/dt

Note

- (1) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;
 Pd = Forward power loss = $I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6);
 Pd_{REV} = Inverse power loss = $V_{R1} \times I_R (1 - D)$; I_R at $V_{R1} = 80\%$ rated V_R

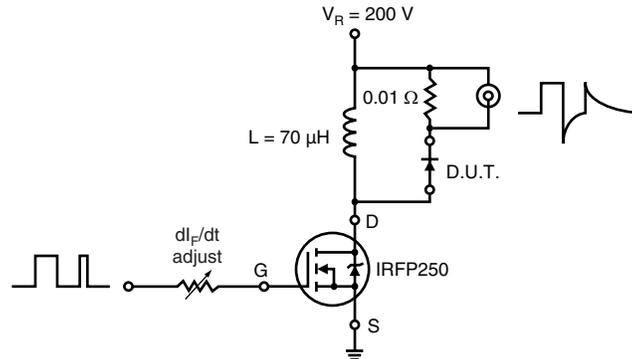
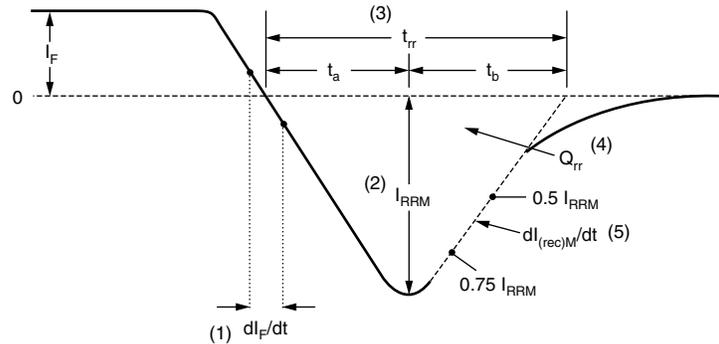


Fig. 9 - Reverse Recovery Parameter Test Circuit



- | | |
|---|---|
| <p>(1) di_F/dt - rate of change of current through zero crossing</p> <p>(2) I_{RRM} - peak reverse recovery current</p> <p>(3) t_{rr} - reverse recovery time measured from zero crossing point of negative going I_F to point where a line passing through $0.75 I_{RRM}$ and $0.50 I_{RRM}$ extrapolated to zero current.</p> | <p>(4) Q_{rr} - area under curve defined by t_{rr} and I_{RRM}</p> $Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$ <p>(5) $di_{(rec)M}/dt$ - peak rate of change of current during t_b portion of t_{rr}</p> |
|---|---|

Fig. 10 - Reverse Recovery Waveform and Definitions

60EPU06PbF/60APU06PbF



Vishay High Power Products Ultrafast Soft Recovery Diode,
60 A FRED Pt™

ORDERING INFORMATION TABLE

Device code	60	E	P	U	06	PbF
	①	②	③	④	⑤	⑥

- 1** - Current rating (60 = 60 A)
- 2** - Circuit configuration:
 - E = Single diode
 - A = Single diode, 3 pins
- 3** - Package:
 - P = TO-247AC (modified)
- 4** - Type of silicon:
 - U = Ultrafast recovery
- 5** - Voltage rating (06 = 600 V)
- 6** -
 - None = Standard production
 - PbF = Lead (Pb)-free

LINKS TO RELATED DOCUMENTS	
Dimensions	http://www.vishay.com/doc?95001
Part marking information	http://www.vishay.com/doc?95006



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